



# Navitas Semiconductor Investor Update

March 2026



*Electrify Our World™*

# Notice

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**Navitas 1.0**  
**Product and technology innovation**  
2014-2024

**Navitas 2.0**  
**Sustainable growth from High Power markets driven by AI catalyst**  
2025+



### **Market Focus – High Power Markets - High Growth, Higher Value**

High-power markets: AI data centers, energy and grid infrastructure, performance computing, and industrial electrification – away from mobile and low end consumer



### **Technological Leadership**

Benefiting from 10+ years of pioneering technology leadership, product innovation and system expertise in GaN, and high reliability GeneSiC™ proprietary SiC technology, informed by customer requirements through strategic partnerships



### **Operational Efficiency**

Streamlined and geographically rebalanced organization, technology partnerships with scalable U.S. foundries, advanced packaging and module partners, solution offerings through collaborations



### **Financial Discipline**

Prioritized investments and a shift towards higher value programs in high power markets with focus on scalable and consistent growth

*One of the very few suppliers offering full spectrum of **SiC** and **GaN** products and solutions expertise to support impending shifts in power architecture driven by AI revolution*

## AI Datacenters



GaN / SiC

## Grid & Energy Infra.



SiC

## Performance Computing



GaN

## Industrial Electrification



GaN / SiC

<b>2030 SAM</b>	<b>\$1.4-2.5 B</b>	<b>\$1-1.8 B</b>	<b>\$0.4 B</b>	<b>\$0.7 B</b>
<b>CAGR 2025-30</b>	<b>66% - 87%</b>	<b>63% - 82%</b>	<b>110%</b>	<b>40%</b>
<b>Growth Drivers</b>	AC/DC PSU, 800V high voltage data center	High reliability, efficiency and density grid-tied applications, including SST, BESS, Utility Solar	Adoption in high power chargers & PSUs	Robotics, industrial pumps, high power inverters, renewable energy

Included in SAM
  Included in TAM
  Excluded from TAM

Current Products
Future Products

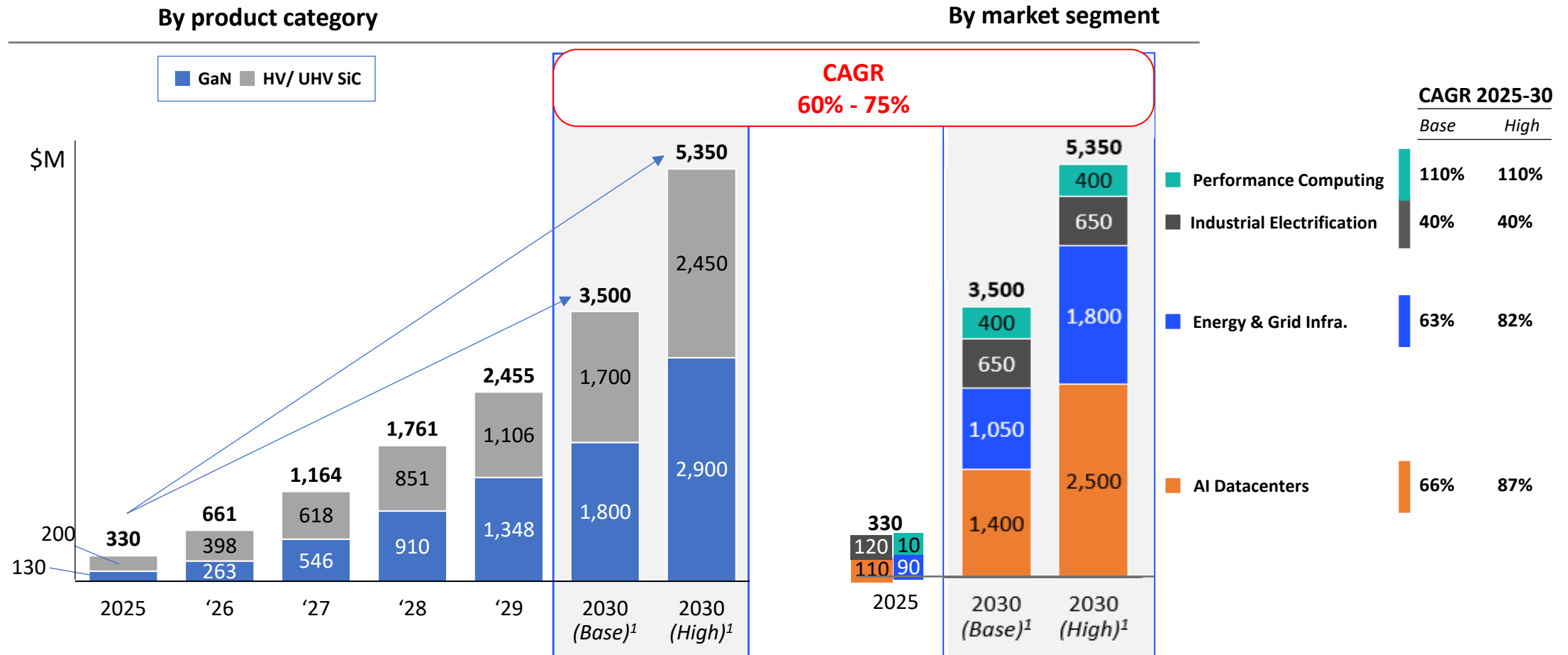
Area	Categories							
<b>Material</b>	<div style="display: flex; justify-content: space-between; align-items: center;"> <div style="background-color: #0056b3; color: white; padding: 10px; border: 1px solid black;">Gallium Nitride (GaN)</div> <div style="background-color: #0056b3; color: white; padding: 10px; border: 1px solid black;">Silicon Carbide (SiC)</div> <div style="border: 1px solid black; padding: 10px;">Silicon</div> </div>							
<b>Voltage<sup>1</sup></b>	<p><b>Gallium Nitride (GaN)</b></p> <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="border: 2px dashed black; padding: 10px; background-color: #0056b3; color: white;">                     LV ( &lt; 100V )                 </div> <div style="padding: 10px; background-color: #0056b3; color: white;">                     MV ( 100V - 650V )                 </div> <div style="padding: 10px; background-color: #0056b3; color: white;">                     HV ( 650V - 1200V )                 </div> <div style="border: 2px dashed black; padding: 10px; background-color: #0056b3; color: white;">                     UHV ( &gt; 1200V )                 </div> </div> <p><b>Silicon Carbide (SiC)</b></p> <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="padding: 10px; background-color: #a6a6a6;">                     LV ( 400V – 750V )                 </div> <div style="padding: 10px; background-color: #0056b3; color: white;">                     HV ( 1200V - 1700V )                 </div> <div style="padding: 10px; background-color: #0056b3; color: white;">                     UHV ( 2000V to 10 kV )                 </div> </div>							
<b>End markets</b>	<table border="1" style="width: 100%; text-align: center;"> <tr> <td style="background-color: #0056b3; color: white; padding: 10px;">AI Datacenters</td> <td style="background-color: #0056b3; color: white; padding: 10px;">Industrial Electrification (including Robotics)</td> <td style="background-color: #a6a6a6; padding: 10px;">Mobile</td> <td rowspan="2" style="background-color: #a6a6a6; padding: 10px; vertical-align: middle;">Others low power markets (e.g., low end consumer, home appliances..)</td> </tr> <tr> <td style="background-color: #0056b3; color: white; padding: 10px;">Energy &amp; Grid Infrastructure</td> <td style="background-color: #0056b3; color: white; padding: 10px;">Performance Computing</td> <td style="background-color: #a6a6a6; padding: 10px;">Automotive (EVs)</td> </tr> </table>	AI Datacenters	Industrial Electrification (including Robotics)	Mobile	Others low power markets (e.g., low end consumer, home appliances..)	Energy & Grid Infrastructure	Performance Computing	Automotive (EVs)
AI Datacenters	Industrial Electrification (including Robotics)	Mobile	Others low power markets (e.g., low end consumer, home appliances..)					
Energy & Grid Infrastructure	Performance Computing	Automotive (EVs)						

1: **LV**: Low Voltage, **MV**: Medium Voltage, **HV**: High Voltage, **UHV**: Ultra-high Voltage

Source: Navitas

# Total SAM Growing at 60-75% CAGR to \$3.5 – \$5.4B in 2030

## Navitas SAM

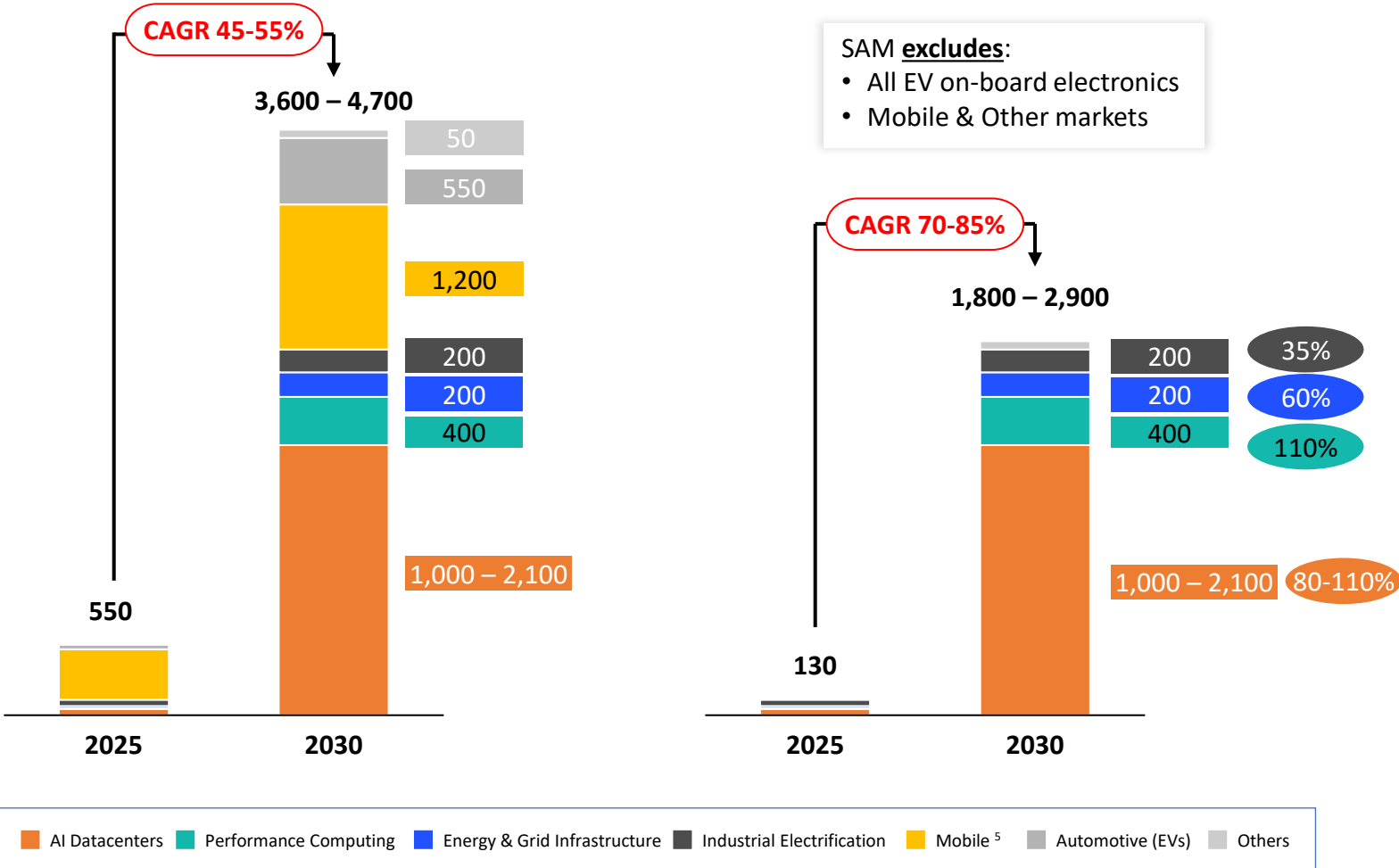


1. 2030 SAM: Base case assumes moderate penetration of AI datacenters with total 2030 demand of 219 GW, moderate adoption of GaN and SiC in energy & grid infrastructure; High case assumes accelerated penetration of AI datacenters with total 2030 demand of 298 GW, faster growth of energy & grid infrastructure power electronics with accelerated adoption of GaN and SiC

# GaN: SAM Growing 70-85% CAGR to ~\$1.8 – 2.9B in 2030

GaN power devices TAM, \$M

Navitas SAM (GaN only), \$M



## Key growth drivers



### AI Datacenters

Datacenter HVDC power conversion and delivery, energy storage (BBUs, CBUs), etc



### Performance computing

High-power, high-density chargers as portable computers evolve with AI-native processing



### Energy and grid infrastructure

HVDC transmission systems, grid-tied inverters in utility-scale renewable energy farms, BESS etc.



### Industrial electrification

Non-EV traction systems (e.g., rail, heavy machinery, ATEs), high-efficiency industrial motor drives, robotics etc.

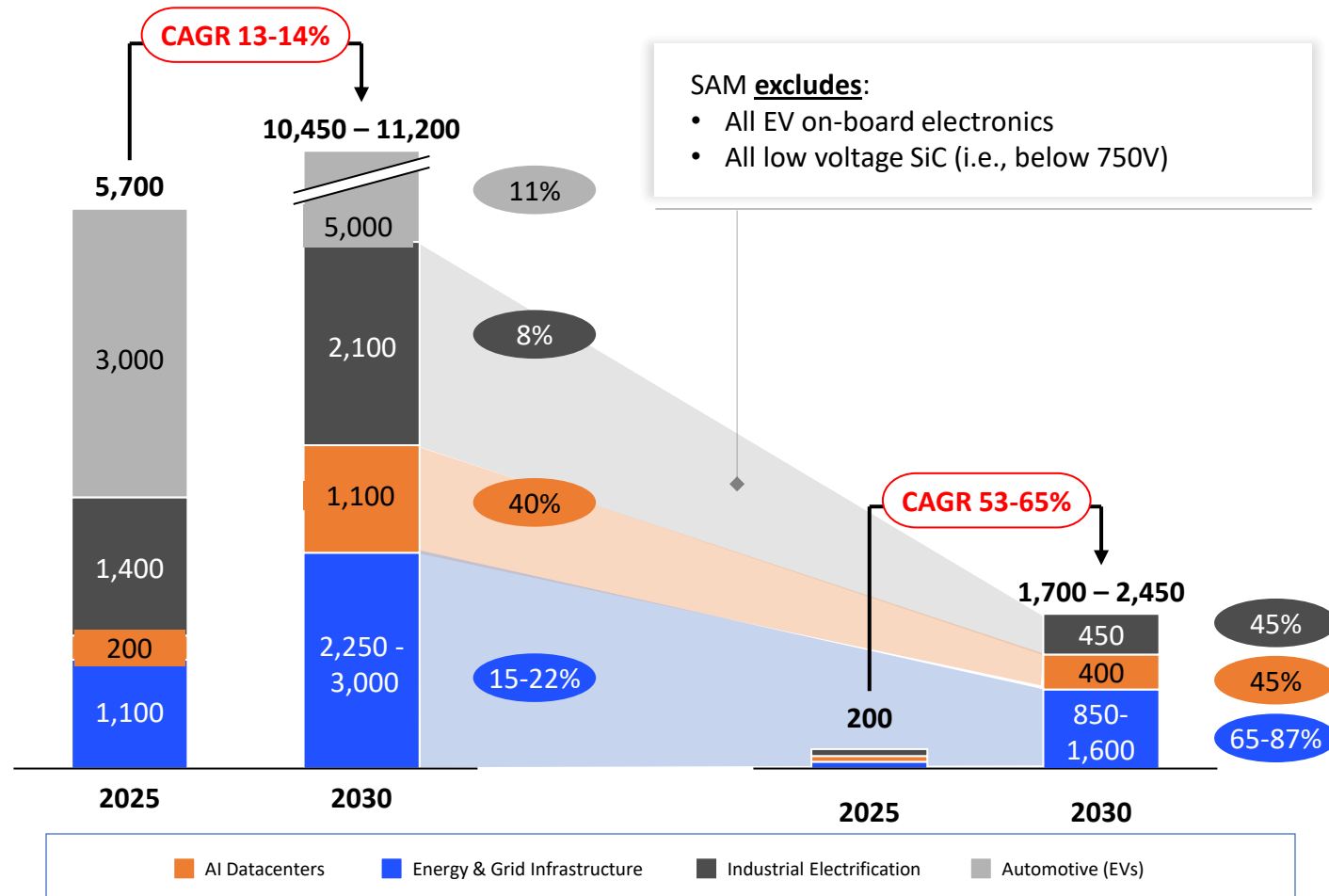
Assumptions 2030: Penetration of non-commoditized GaN devices – Industrial: 85%; Computing and high-power delivery: 95%

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 Source: Yole Compound Semi market monitor Q3 2025, McKinsey Center for Future of Mobility, McKinsey datacenter infrastructure model, IDC Smartphone market insights

# SiC: SAM Growing 53-65% CAGR to ~\$1.7 – 2.5B in 2030; ~4x Faster than TAM

SiC power devices TAM, \$M

Navitas SAM, \$M



## Key growth drivers



### AI Datacenters

High voltage AC/DC, DC/DC converters in datacenter power tree, PSUs, BBUs, UPS, cooling systems etc.



### Energy & grid infrastructure

SSTs<sup>1</sup> for HVDC transmission, renewable grid integration (e.g., utility-scale solar farms), BESS<sup>2</sup>, PF<sup>3</sup> correction systems, etc.



### Industrial electrification

Non-EV traction systems (e.g., rail, heavy machinery, ATEs), Robotics, Megawatt charger systems, high-efficiency industrial motor drives, high-power induction heating systems etc.

1. Solid State Transformers

2. Battery Energy Storage System

3. Power Factor

Source: Yole Compound Semi market monitor Q3 2025, McKinsey Center for Future of Mobility, McKinsey datacenter infrastructure model

# AI Datacenters: Architectural Shift to Multi-MW Racks

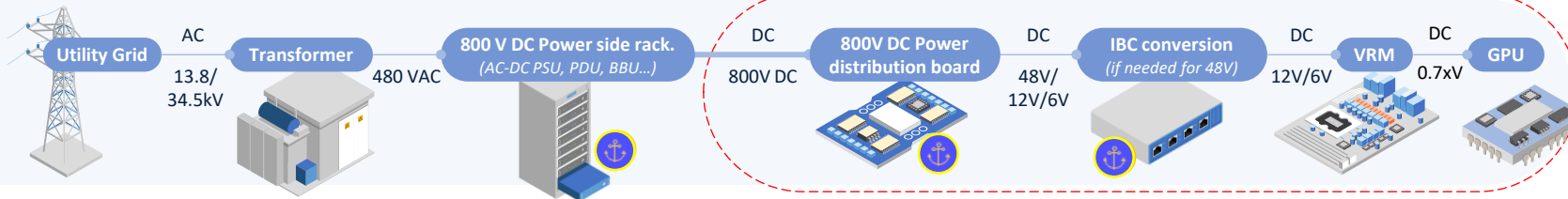
Navitas anchor products / capabilities

## Today: Centralized AC with rack level AC-DC conversion



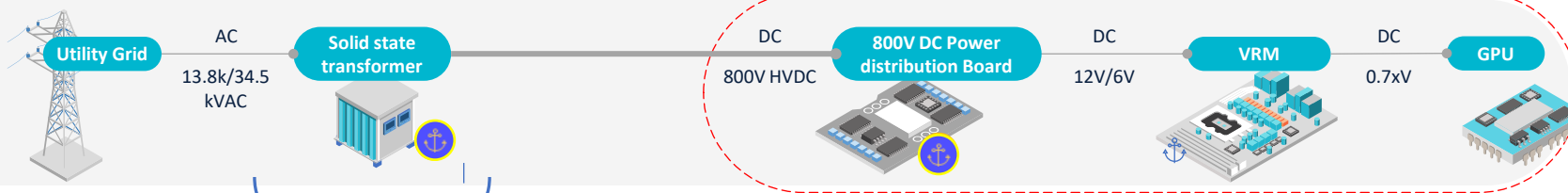
Server Rack: <250kW

## Short-to Mid-term evolution – 800V HVDC



Server Rack: >250kW

## Mid- to Long-term evolution – 800V HVDC

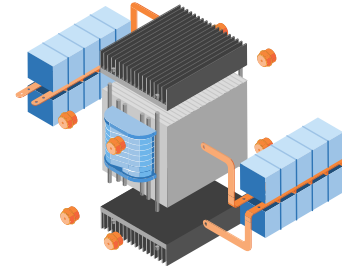
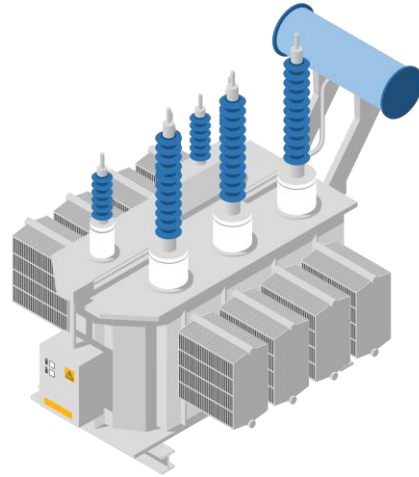


Server Rack: >600kW

*SSTs to further accelerate demand for MV/HV power semis*

Energy efficiency	Typical power tree	Wideband Gap content per MW
80-85%	95+% Silicon-based	-
Up to 90%	Significant GaN / SiC	\$10K-\$20K
Over 90%	Accelerating GaN / SiC	\$25K-\$35K

Note: PDU – Power Distribution Unit; PSU – Power Supply Unit; BBU – Battery Backup Unit; UPS – Uninterrupted Power Supply; IBC – Intermediate Bus Converter; VRM - Voltage Regulator Module  
Source: Navitas, Expert interviews



**Conventional Transformer**

**Medium Frequency Isolation Transformer**

**Figures of merit**

<b>Volumetric power density</b>	0.2kW / L	25kW / L	↑ <b>125x</b>
<b>Gravimetric power density</b>	0.5kW / Kg	25kW / Kg	↑ <b>50x</b>
<b>Operating frequency</b>	60Hz	100KHz	↑ <b>1600+x</b>
<b>Efficiency</b>	< 95%	> 98%	↑ <b>5+pp</b>
<b>Size</b>	-	20x reduction	↓ <b>20x</b>

	GaN + SiC	GaN	SiC	Comments
<b>Total \$ content per MW</b>	~ \$25K - \$35K	~ \$10K - \$15K	~ \$15K - \$20K	Estimate factoring ASP trend, redundancy and number of devices per system. Using same assumption as the base SAM (moderate penetration of AI Data Centers with total demand in 2030 of 219GW, 50% of AI D/C using 800V HVDC)
<b>Inside AI Data Center</b>		~ \$10K - \$15K Mostly driven by 800V HVDC	~ \$5K - \$8K Mostly driven by AC/DC PSU	Not factoring \$2-3 of SiC JFET for circuit protection and hotswap
<b>Outside Data Center (Energy &amp; Grid Infra.)</b>			~ \$10K - \$12K Mostly driven by SST, BESS	The energy grid re-architecture represents a very large opportunity for UHV (>2Kv) SiC and V-Gan (2030)



## Proven Leadership in Next-Gen Power Semiconductors

Portfolio, technology moats and expertise in both GaN and SiC

GaN: Pioneered market adoption with 300Mu+ shipped and large patent portfolio

SiC: Leader in high voltage to ultra high-voltage SiC with exceptional reliability and figure of merits



## Strategic Transformation to High-Value Markets

Focused investment in higher power markets to drive scalable growth

AI data centers, grid and energy infrastructure, performance computing and industrial electrification

Advanced technology partnership with leading foundries



## Well Positioned to Execute with Strong Balance Sheet

Q4 2025 cash balance of \$237M; zero debt

Committed to financial discipline and path to profitability

***Pureplay opportunity in a next-gen, high-power technology provider***



*Electrify Our World™*